

# Pixel vertex detector

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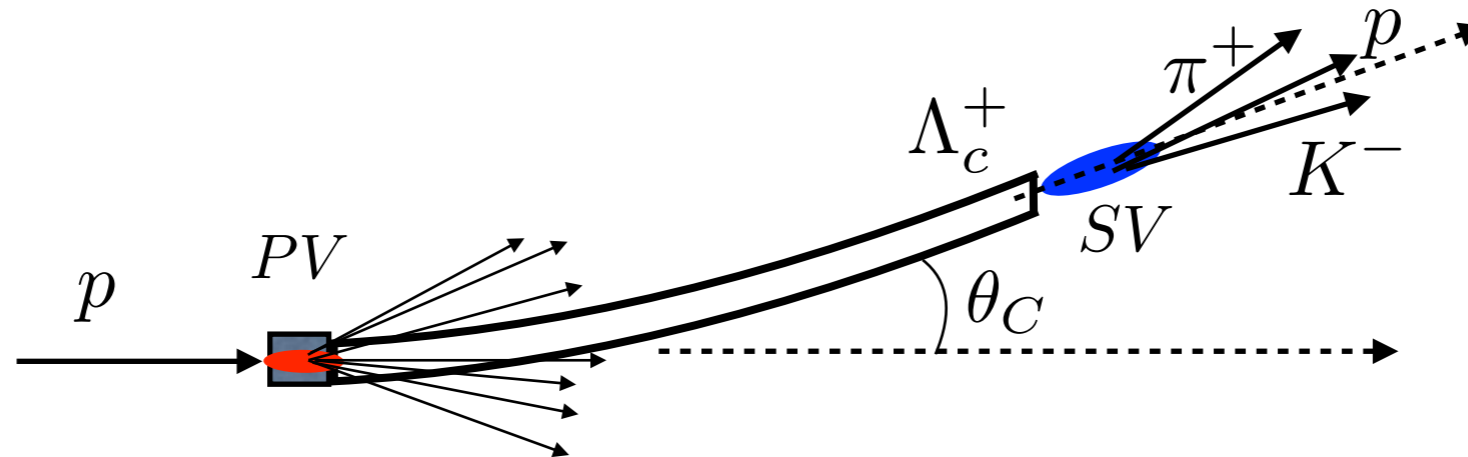
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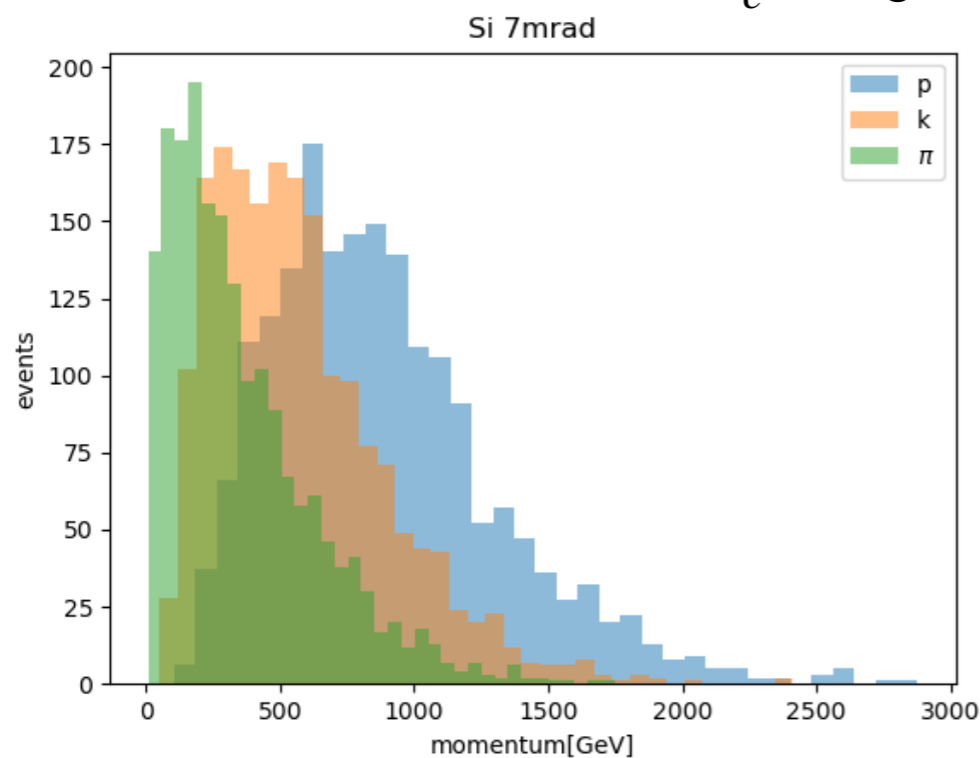
SELDOM [webpage](#)  
 [@SeldomTeam](#)

# $\Lambda_c^+$ signal event topology

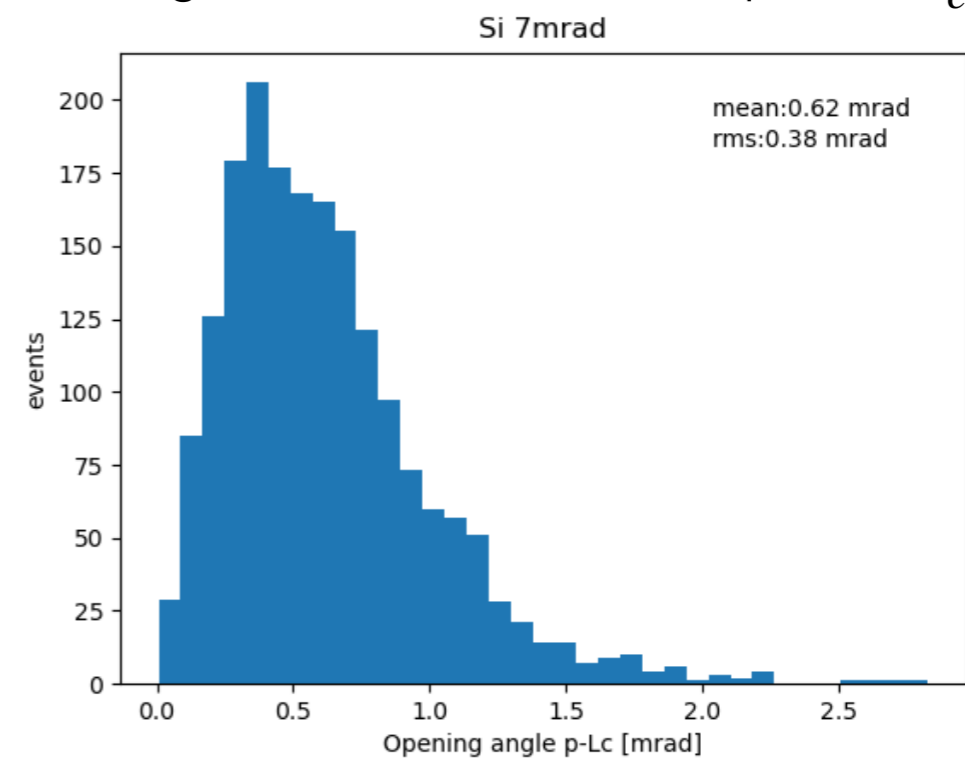
- ▶ Average momentum of 1 TeV for channeled  $\Lambda_c^+$  baryons for bending angle  $\theta_C = 7$  mrad



Momentum distribution of  $\Lambda_c^+$  daughters



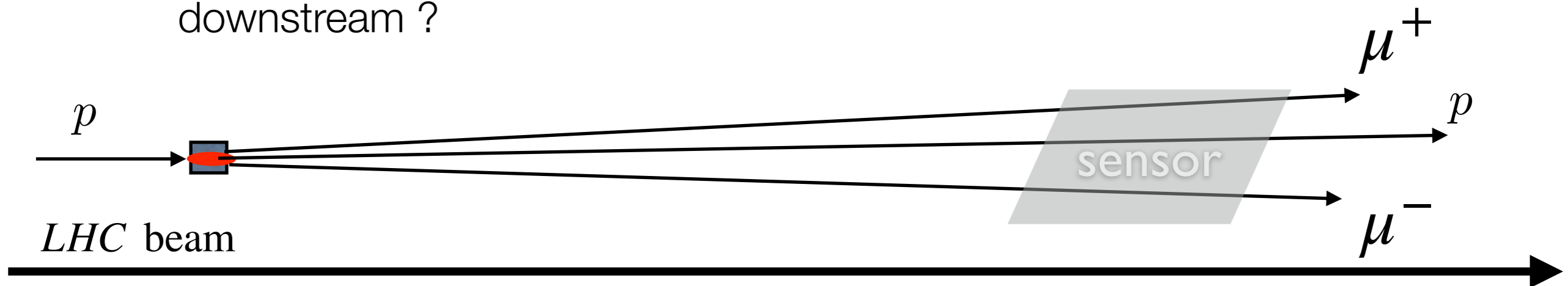
Angular distance between  $p$  and  $\Lambda_c^+$



Plots from Sara

# Photo-production

- ▶ Very forward production at  $\eta \gtrsim 5$ . For example  $\gamma p \rightarrow J/\psi(\mu^+\mu^-)p$  with  $p_{J/\psi} \approx 500$  GeV
- ▶ Need to reconstruct deflected proton,  $\theta_p \approx 250$   $\mu\text{rad}$ , and  $\mu^+\mu^-$  pair to measure the  $m(J/\psi p)$  invariant mass
- ▶ Veto additional particles in the event to identify photo-production events. Hermetic detector is required. Use veto detectors far downstream ?



- ▶ Pixel detector intercepts the proton deflected beam to improve the reconstruction of photo-production events
- ▶ What is the minimum acceptable distance from the main LHC beam? TOTEM, ALFA go at  $10\sigma \approx 1$  mm

# Pixel detector specifications

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Simulation studies on minimum bias events (flux  $10^6$  p/s, 2 cm thick W target) and signal  $\Lambda_c^+ \rightarrow pK^-\pi^+$  decays

- Very forward production. Track pseudo-rapidity  $\eta \geq 5$
- Very fine granularity  $\leq 100$   $\mu\text{m}$  pitch
- Hit rate: up to 200 MHz/cm<sup>2</sup>
- Radiation hardness: fluence up to  $10^{15}$  n<sub>eq</sub>/cm<sup>2</sup>
- High momentum tracks, material budget per layer  $\sim 1\%$   $X_0$
- Instrumented area per layer  $\sim 10 \times 10$  cm<sup>2</sup>
- Distance from the LHC beam  $\sim 5$  mm ?
- Detector length  $\sim 1$  m

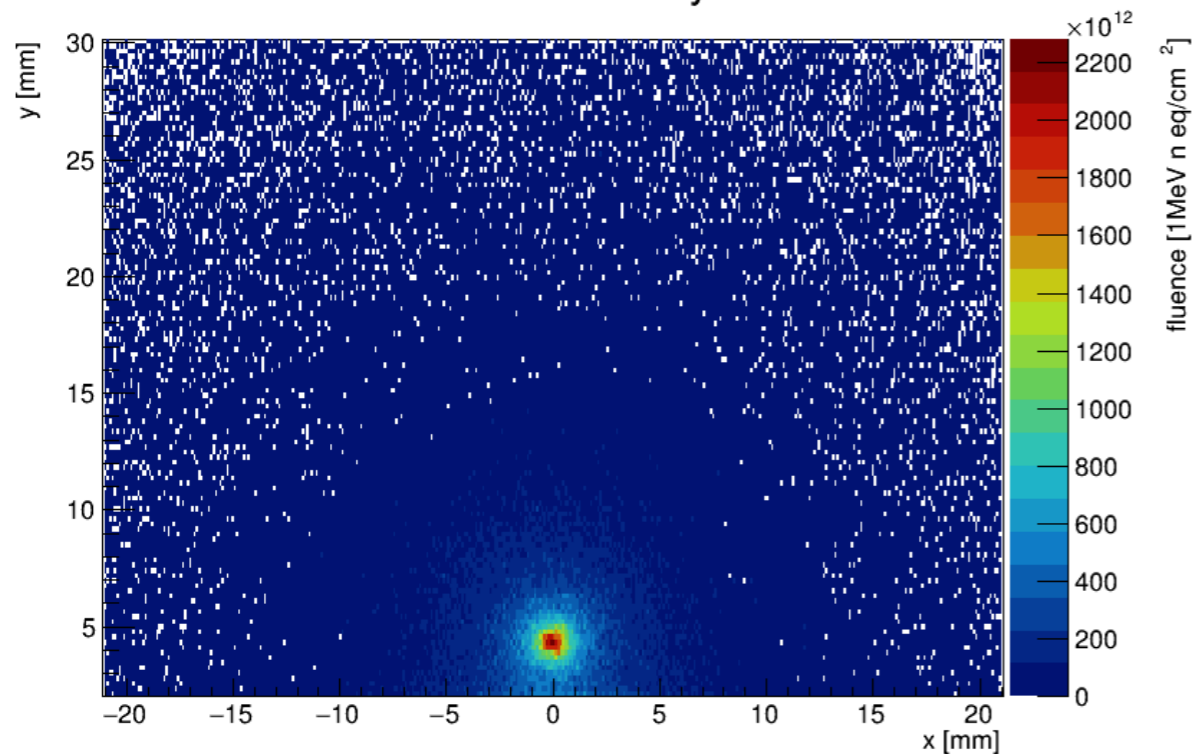
# Fluence on detector layers

- ▶ Corresponding to  $4 \times 10^{13}$  PoT ( $\approx 8$  years of data taking at  $10^6$  p/s)

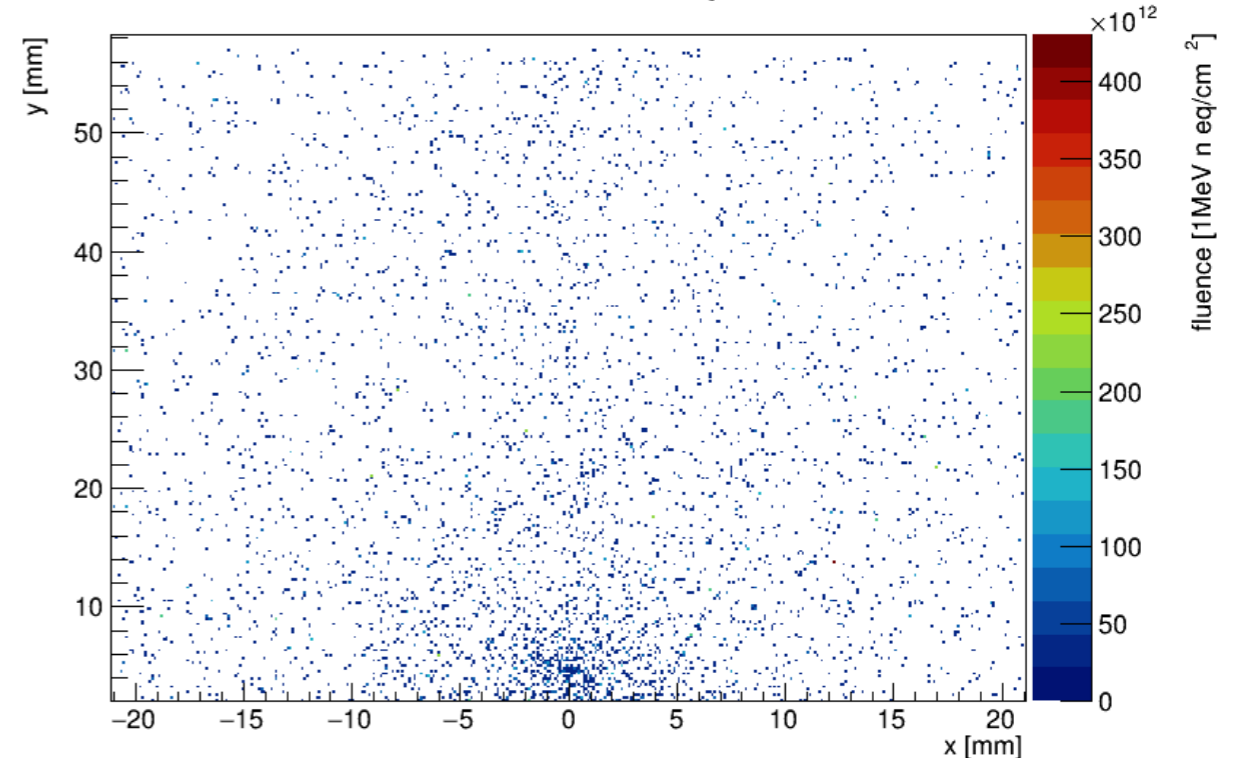
Before the magnet  $\approx 10^{15}$  (1 MeV  $n_{eq}$ )/cm<sup>2</sup>

After the magnet  $\approx 10^{14}$  (1 MeV  $n_{eq}$ )/cm<sup>2</sup>

Fluences of layer 0



Fluences of layer 4



Plots from  
Sara, Elisabetta

- ▶ Radiation concentrated in a very small region (few mm<sup>2</sup>).
- ▶ **Silicon detectors** can cope with such fluence. Mitigation strategy:
  - move the detector in  $x$ ,  $y$  to distribute the radiation on a wider region (requires a motion system inside the pot)
  - sensor cooling, operations at  $T < 0$  C°

# Rates on detector layers

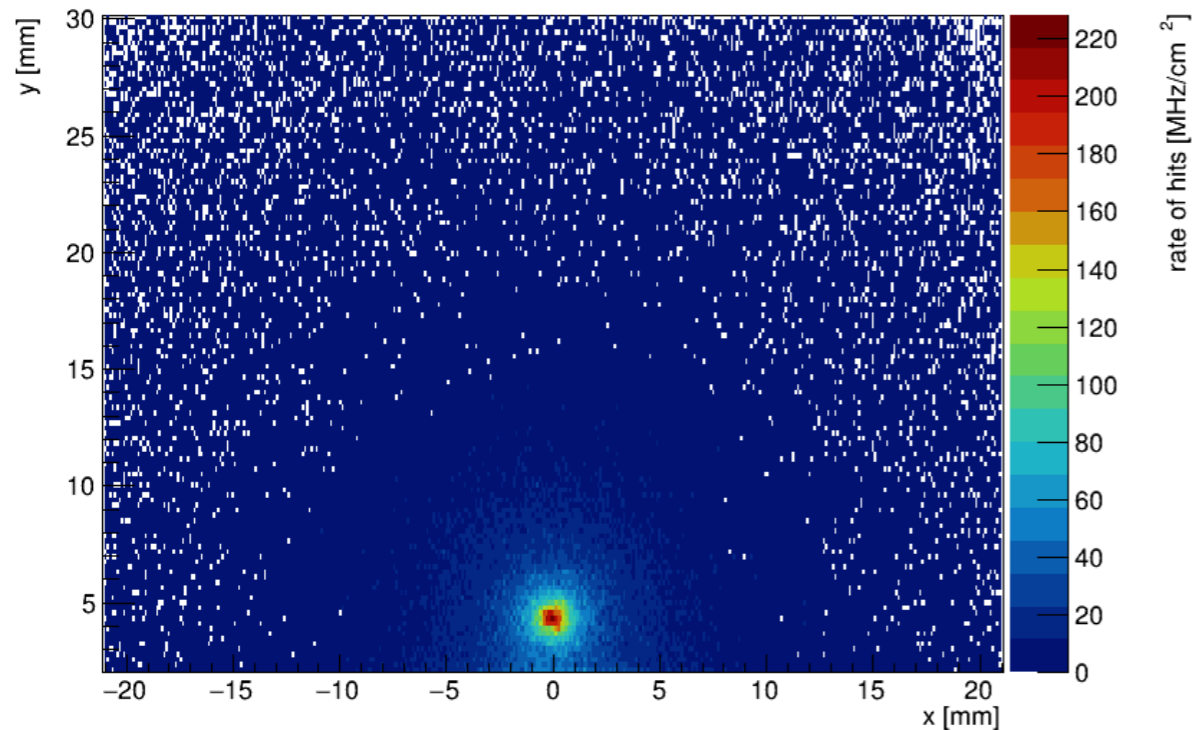
- ▶ Corresponding  $1.0 \times 10^6$  p/s on 2.0 cm thick W target

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Sara, Elisabetta

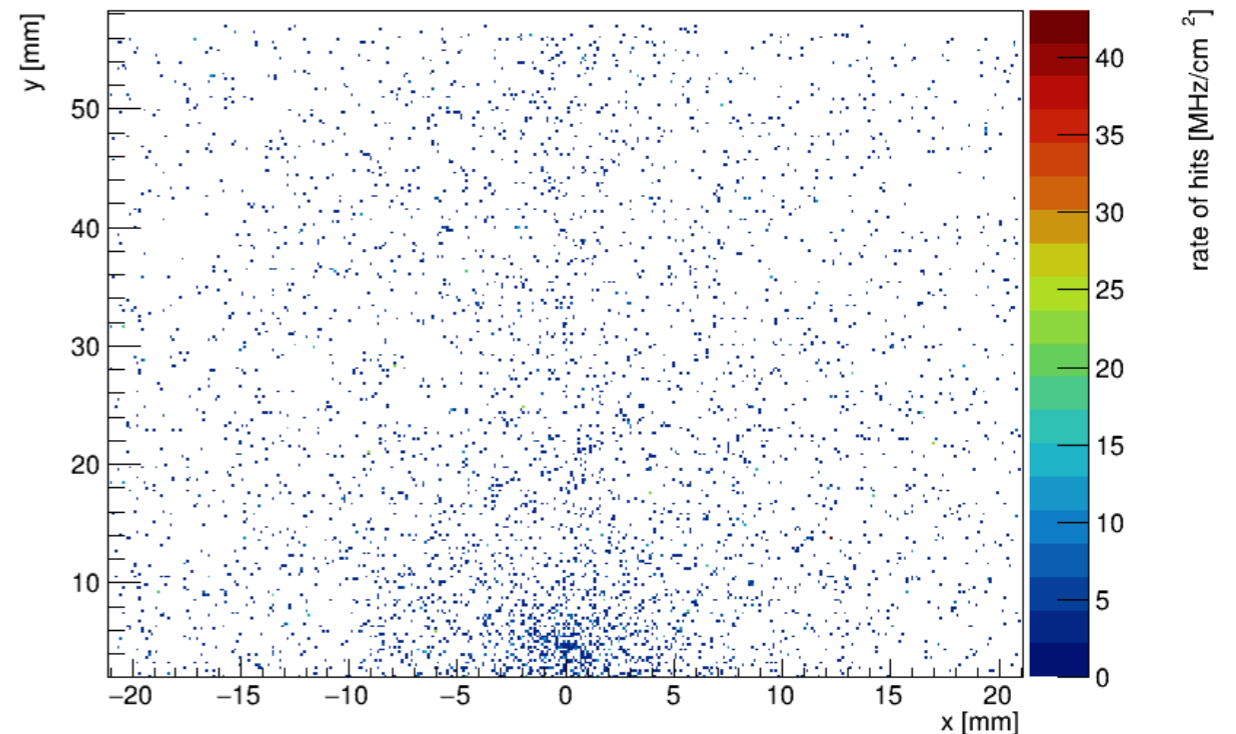
Before the magnet  $\approx 200$  MHz/cm<sup>2</sup>

After the magnet  $\approx 20$  MHz/cm<sup>2</sup>

Rate of layer 0



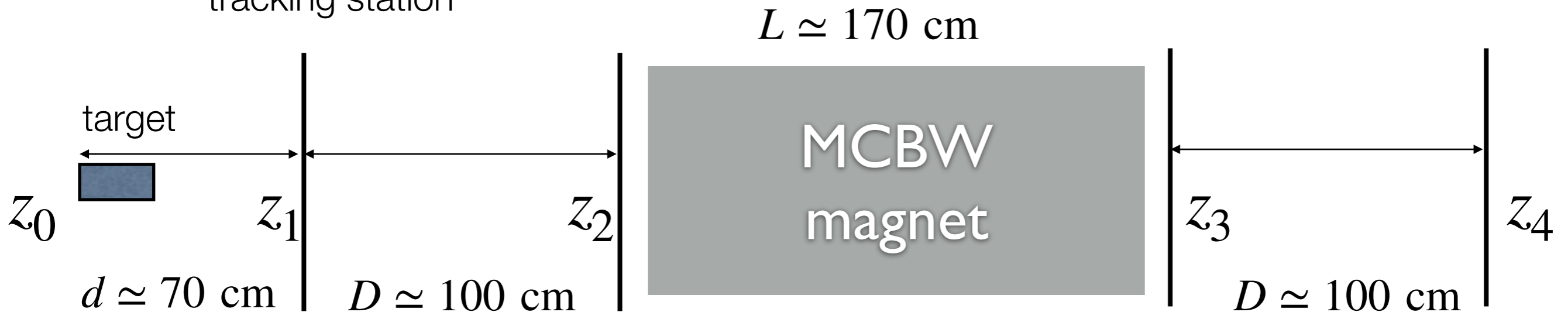
Rate of layer 4



- ▶ High-granularity **pixel detector** before the magnet. At 200 MHz/cm<sup>2</sup>
  - 55  $\mu$ m pixel size, pixel rate = 6.6 kHz ✓ YES
  - 90  $\mu$ m pitch, 5 cm strip length, strip rate = 9 MHz NO

# Vertex detector geometry

tracking station



- ▶ Resolve the 3 tracks on the detector  $d\theta \gtrsim 5 \times \text{pitch} \Rightarrow d \gtrsim 50$  cm with  $\theta \approx 0.5$  mrad, pitch =  $55 \mu\text{m}$
- ▶ Track angle resolution  $\sigma_\theta \approx \sqrt{2}\sigma_x/D = 14 \mu\text{rad}$  with  $\sigma_x \approx 10 \mu\text{m}$
- ▶  $\Lambda_c^+$  decay vertex  $\sigma_{x,y} \approx \left( \frac{z_1^2\sigma_2^2 + z_2^2\sigma_1^2}{(z_2 - z_1)^2} + z_1^2\theta_{\text{ms}}^2 \right)^{1/2} \approx 20 \mu\text{m}$   
 $\sigma_z \approx \sigma_y/\tan\theta_C = 2.8$  mm
- ▶  $\theta_{\text{ms}} \approx 5 \mu\text{rad}$  at 500 GeV and  $x/X_0 = 4\%$

# Spectrometer geometry

tracking station

$L \simeq 170 \text{ cm}$

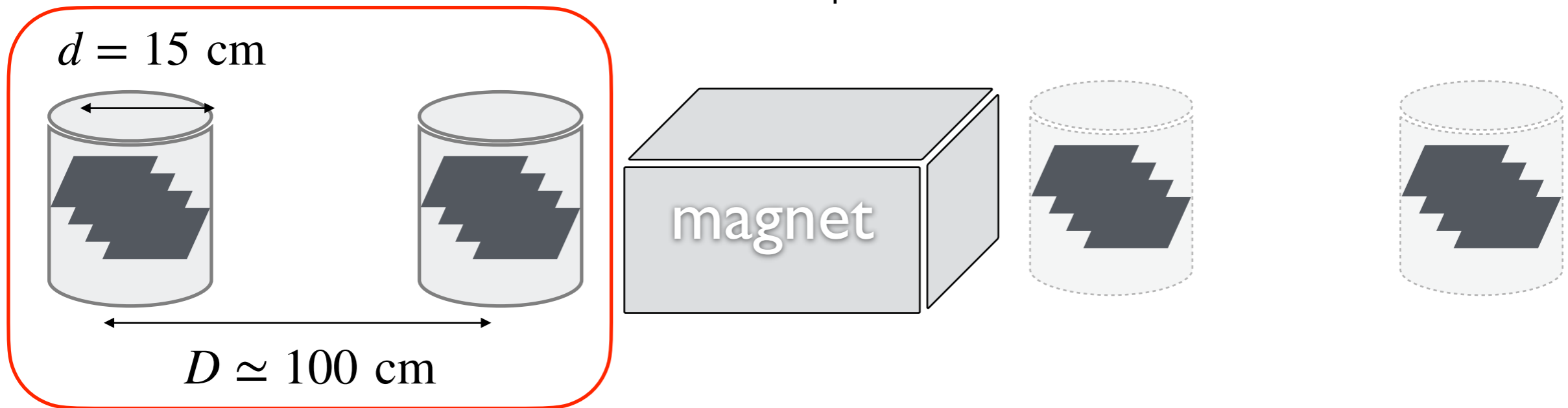


- ▶ Momentum resolution  $\frac{\sigma_p}{p} \approx \frac{2p}{0.3BLD} \sigma_x = 2\%$  (neglecting multiple scattering) with  $p = 500 \text{ GeV}$ ,  $BL = 1.9 \text{ Tm}$ ,  $D = 100 \text{ cm}$ ,  $\sigma_x = 10 \mu\text{m}$
- ▶ Momentum resolution could be improved by reducing  $\frac{\sigma_x}{BLD}$
- ▶ A compact magnet  $L \approx 50 \text{ cm}$  with  $BL \gtrsim 4 \text{ Tm}$  would be beneficial for momentum resolution (x2 improvement) and acceptance/hermeticity (70%  $\rightarrow$  90%) (see Elisabetta's talk)



# Conceptual design for pixel vertex detector

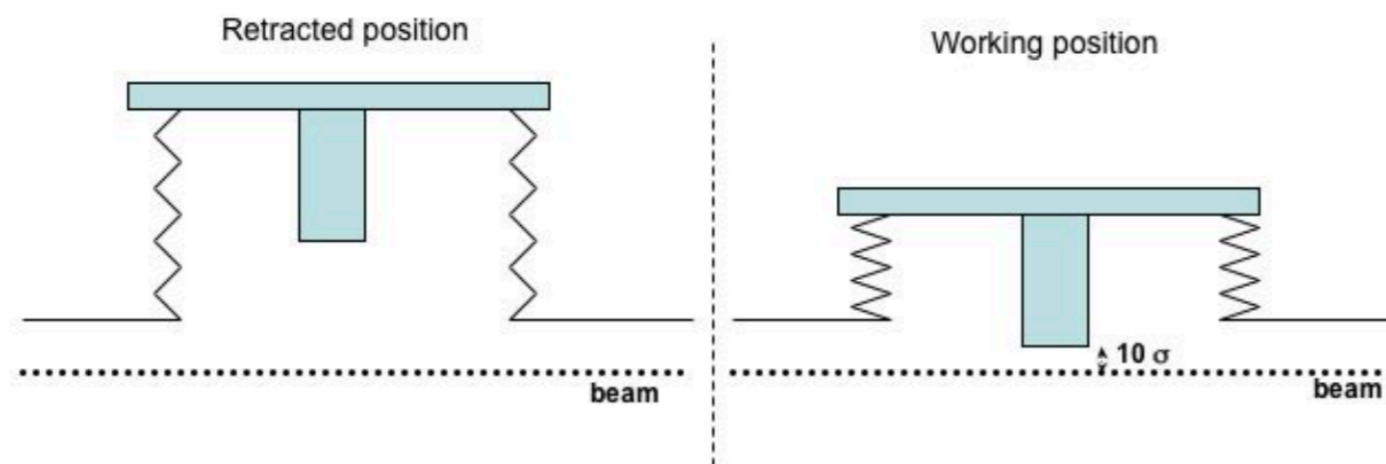
- ▶ Silicon pixel detectors housed in 2 Roman Pots
  - Hybrid pixel sensors: VELO sensors, 4 layers/station
  - Roman Pots: ALFA/TOTEM pots



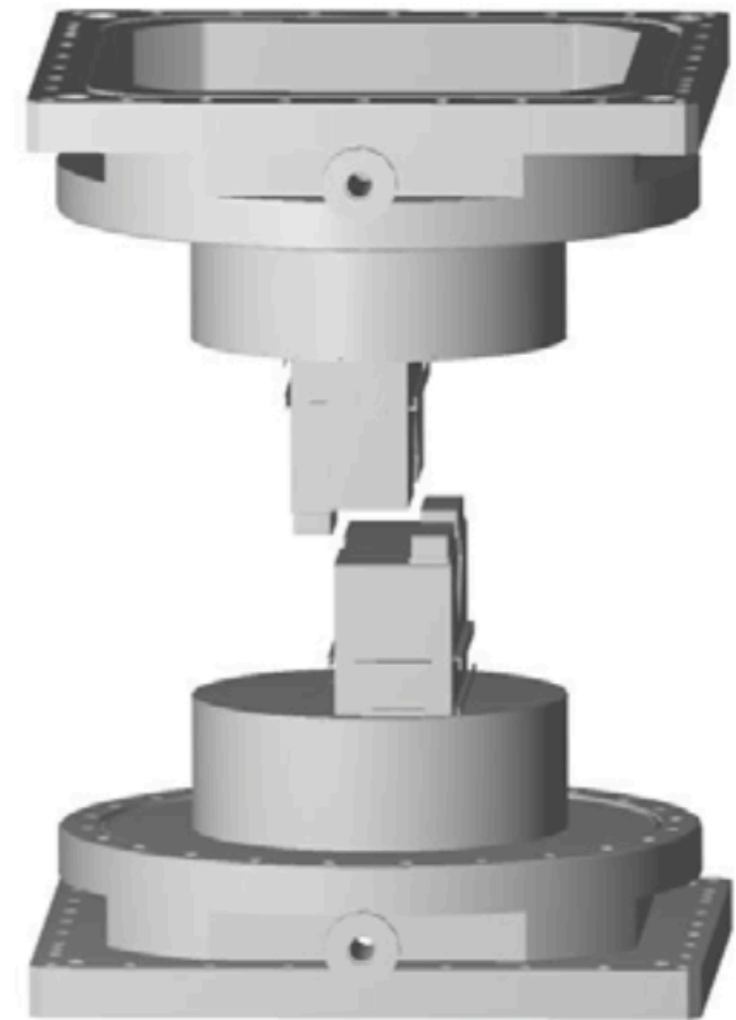
- hit resolution  $\sigma_{\text{hit}} \sim 15 \mu\text{m} \Rightarrow \sigma_x \approx \sigma_{\text{hit}}/\sqrt{4} = 7.5 \mu\text{m}$
- $\sigma_{\text{ms}} \approx D\theta_{\text{ms}} = 4.8 \mu\text{m}$  at 500 GeV and  $x/X_0 = 4 \%$
- $\Lambda_c^+$  vertex position  $\sigma_{\text{vtx}} \sim (0.015, 0.015, 2.1) \text{ mm}$
- track angle  $\sigma_\theta \approx (\sigma_1^2 + \sigma_2^2)^{1/2}/(z_2 - z_1) = 12 \mu\text{rad}$ , with  $\sigma_1 = \sigma_x$ ,  $\sigma_2 = \sigma_1 \oplus \sigma_{\text{ms}}$

# Detector operations in a Roman Pot

- ▶ Roman Pots (RP) are movable devices allowing to perform measurements inside the beam pipe. In ALFA, TOTEM down to  $10\sigma$  ( $\sim 1$  mm) from the main LHC proton beam

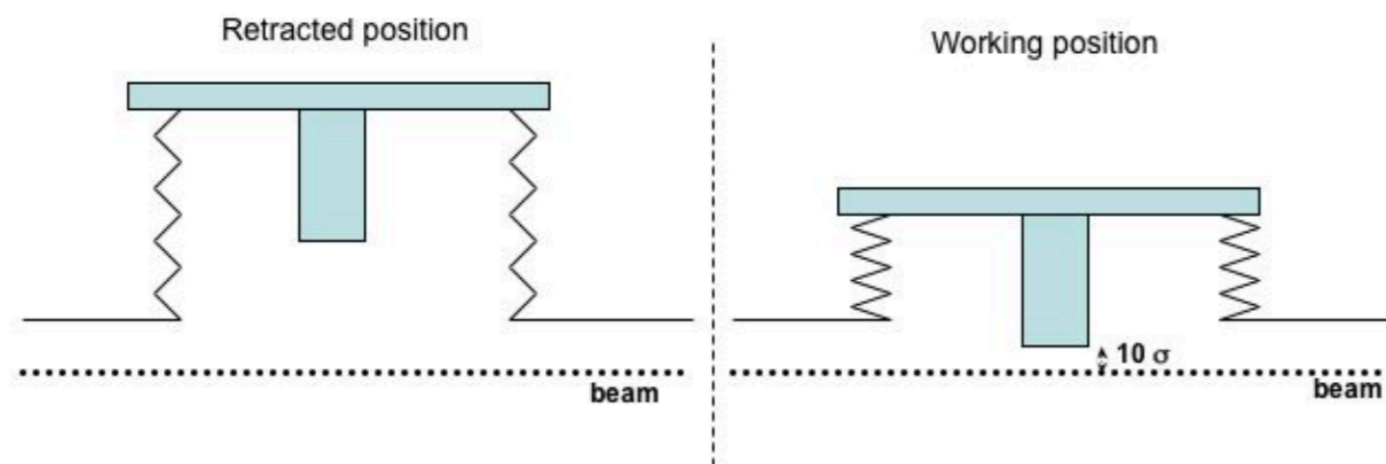


- ▶ Possibility to use 2 vertical pots to increase acceptance and detector hermeticity. Rectangular extrusion dimension  $128 \times 60 \times 46$  mm<sup>3</sup>

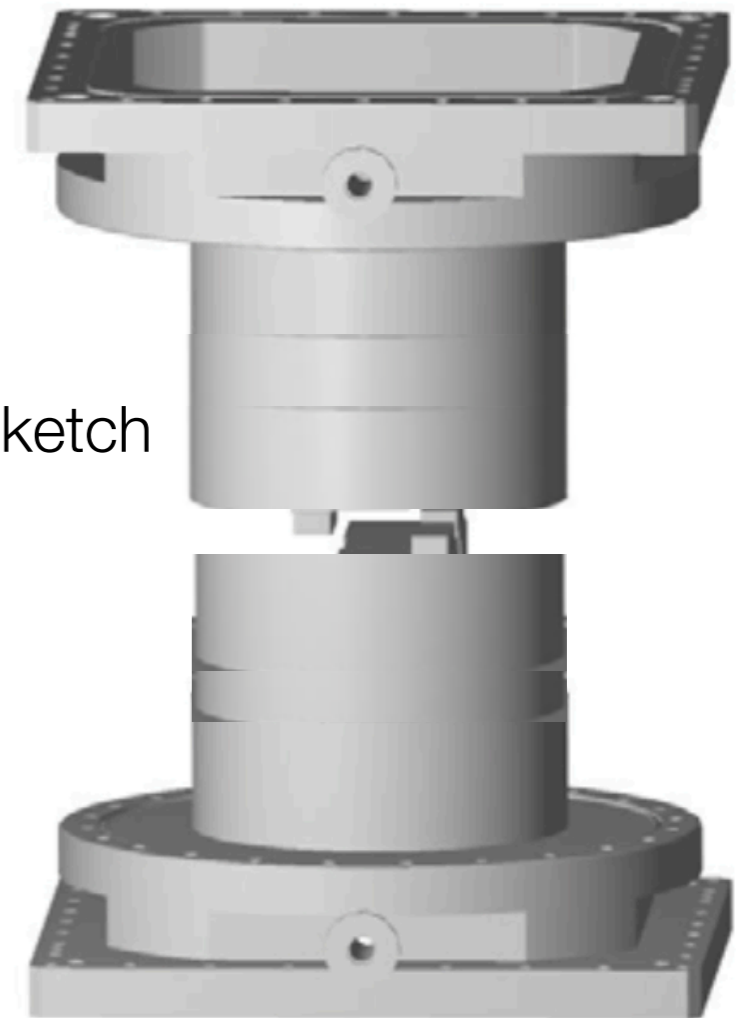


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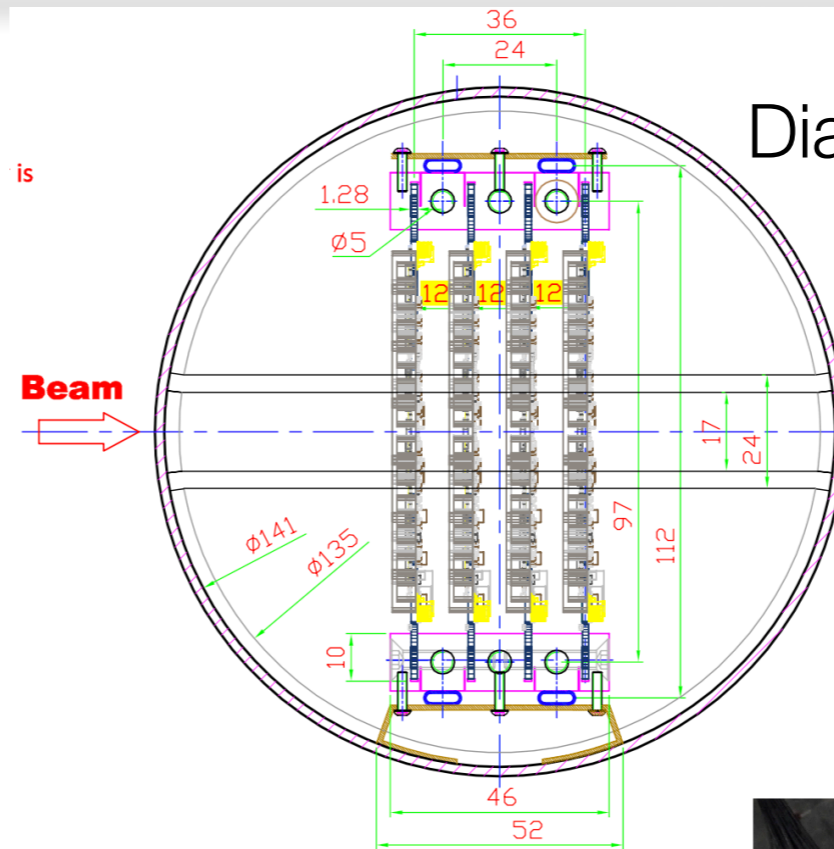
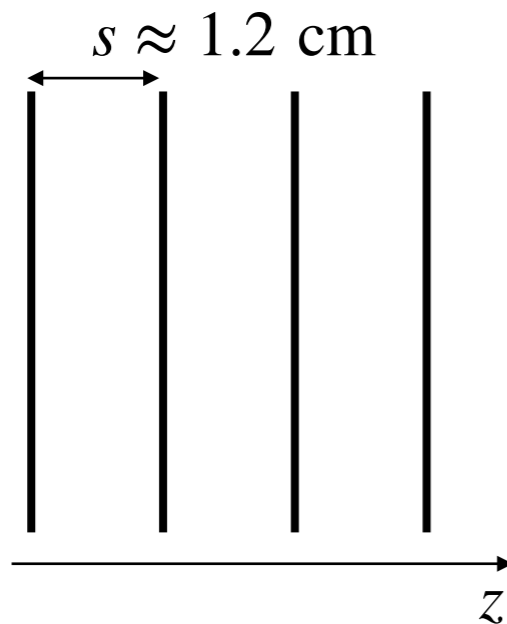


Artistic sketch



- ▶ Possibility to use cylindrical RPs, developed by TOTEM experiment, to increase the space available for the detector package (diameter 15 cm)

# Layers per RP station



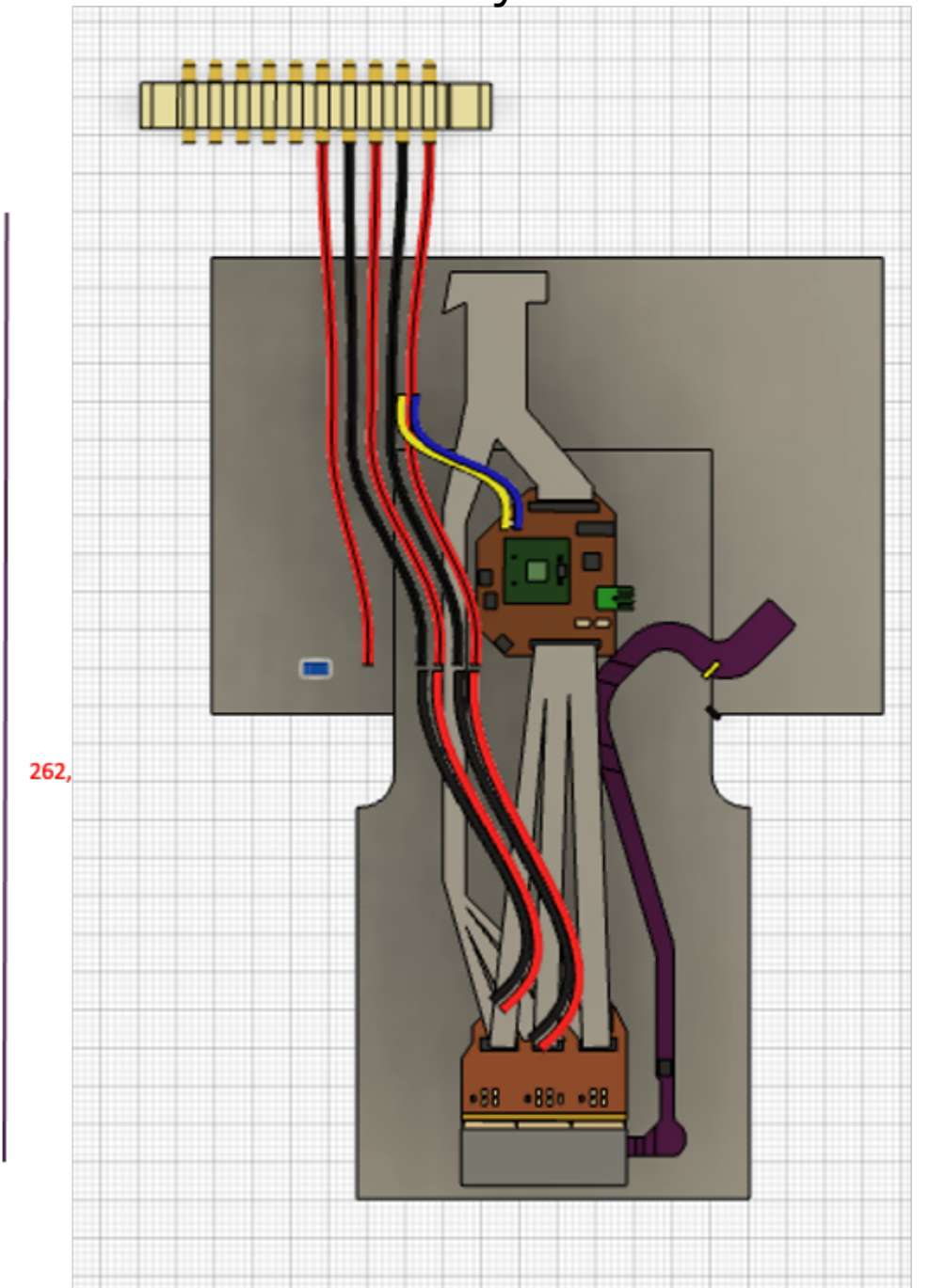
Courtesy of N. Turini  
Diamond detector TOTEM

- ▶ Number of layers  $N \geq 3$  to confirm that the hits belong to a track. Pattern recognition and resolution studies ongoing to determine the optimal number
- ▶ Distance  $s$  between layers determined by the space available in the RP (46 mm along  $z$ ) and the thickness of a sensor module. More space available with cylindrical RPs (150 mm diameter)

# Sensors per layer

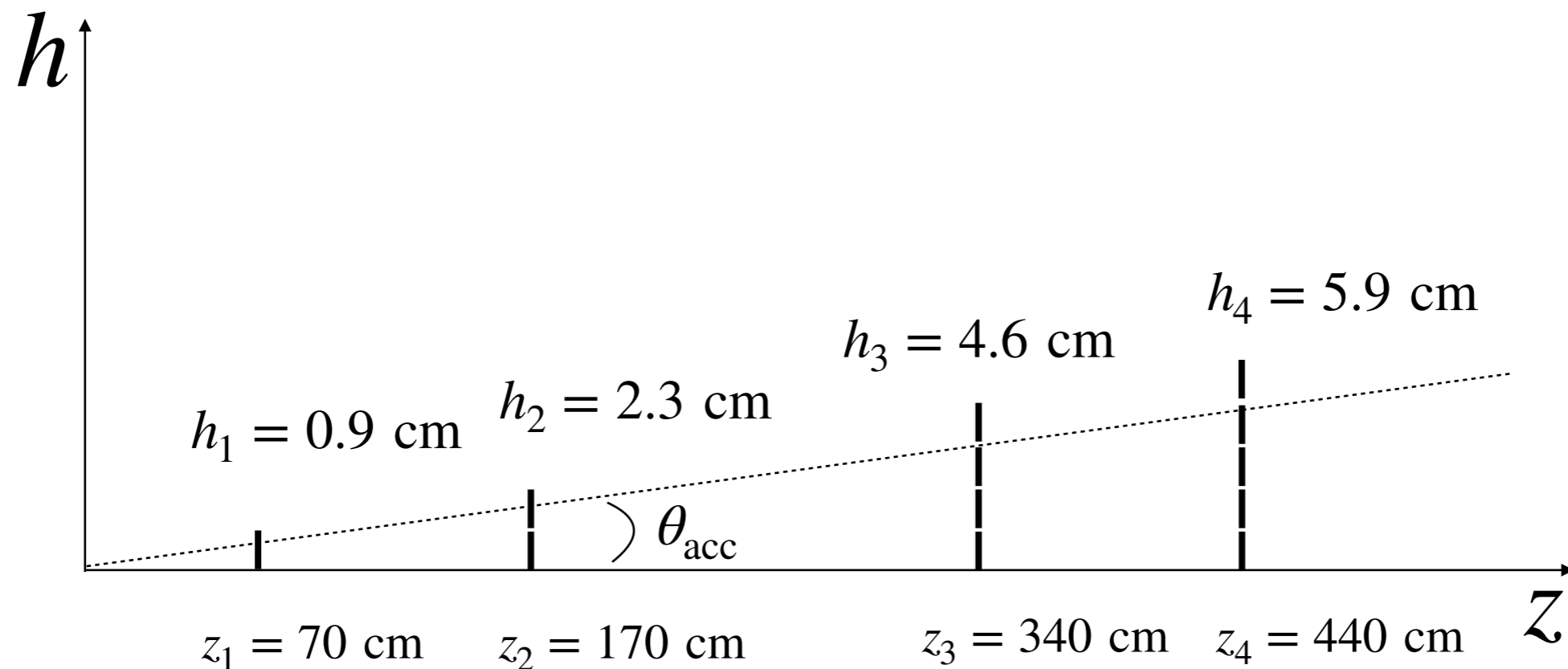
- ▶ VELO tile: 3 ASICs, active area  $14 \times 42 \text{ mm}^2$
- ▶ VELO tile design adapted to fit inside the RP by modifying the geometry of the flex cables (straight instead of curved cables)
- ▶ Multiple tiles can fit in on layer. Design to be developed

Courtesy of S. Cesare



# Spectrometer coverage

- ▶ For a coverage  $\eta \geq 5$ , i.e.  $\theta_{\text{acc}} \sim 13$  mrad, sensor size varies  $h_i = z_i \theta_{\text{acc}}$  but still compact detector in the transverse plane
- ▶ Complementary to LHCb coverage  $2 \leq \eta \leq 5$



# VELO pixel solution

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- ▶ VELO tiles are the baseline solution for the pixel vertex detector
- ▶ Purchased 48 tiles at Hamamatsu. Currently at Advafab for bump-bonding with VELO chips. Ready in February 2024

Pixel sensor parameter	Rating
silicon type	p-type
thickness	200 $\mu\text{m}$
active area	14x42 $\text{mm}^2$
pixel pitch	55 $\mu\text{m}$
full depletion V *	40-150 V
breakdown V *	800 V
leakage current *	20-100 nA

\* at T=25 °C

# VeloPix chip specifications

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Specification	Timepix3	VeloPix
pixel dimension	$55 \times 55 \mu\text{m}^2$	$55 \times 55 \mu\text{m}^2$
matrix size	$256 \times 256$	$256 \times 256$
timewalk	$< 25 \text{ ns}$	$< 25 \text{ ns}$
Time over Threshold range	10 bit	6 bit (calibration mode only)
leakage current compensation (per pixel)	20 nA	20 nA
Time stamp resolution	1.6 ns	25 ns
Time stamp range	18 bit	9 bit
average pixel hit rate	n.a.	600 MHits/s
peak pixel hit rate	80 MHit/s	900 MHits/s
peak super-pixel packet rate	n.a.	520 MHits/s
min. output bandwidth	2.56 Gbit/s	18 Gbit/s
max. pixel hit loss at max. rate	-	1%
power consumption per ASIC	$< 2 \text{ W}$	$< 3 \text{ W}$
radiation hardness	no spec.	$> 400 \text{ Mrad}$
single event upset robust	no	yes

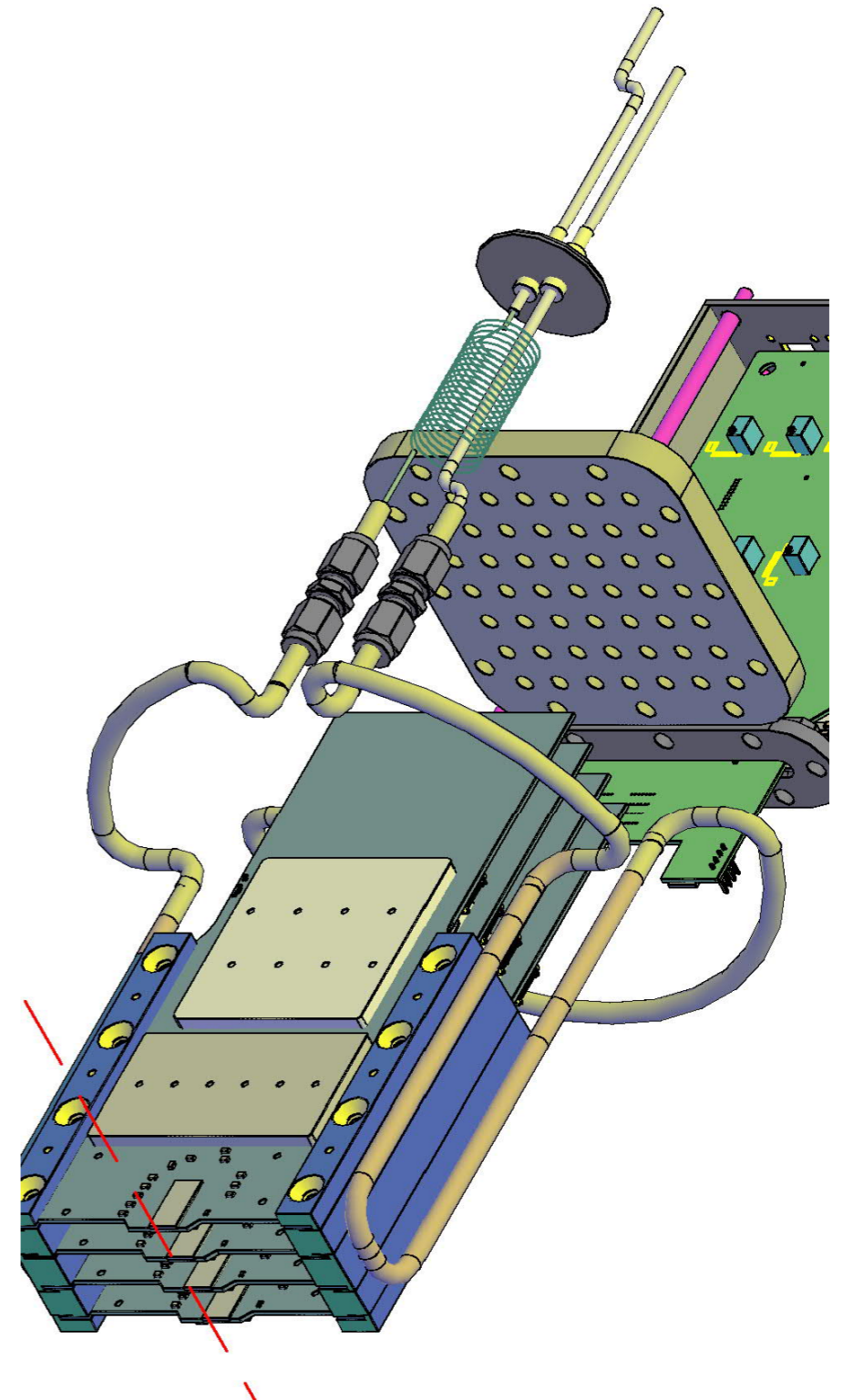
- ▶ VeloPix can cope with  $p$  collisions up to  $10^7$  p/s on 2 cm W target (safe) but not  $10^8$  p/s
  - Analog signal pileup at pixel rate  $> 3$  MHz. Maximum data transfer rate 13.3 M packets/s



# Sensor cooling

Courtesy of N. Turini

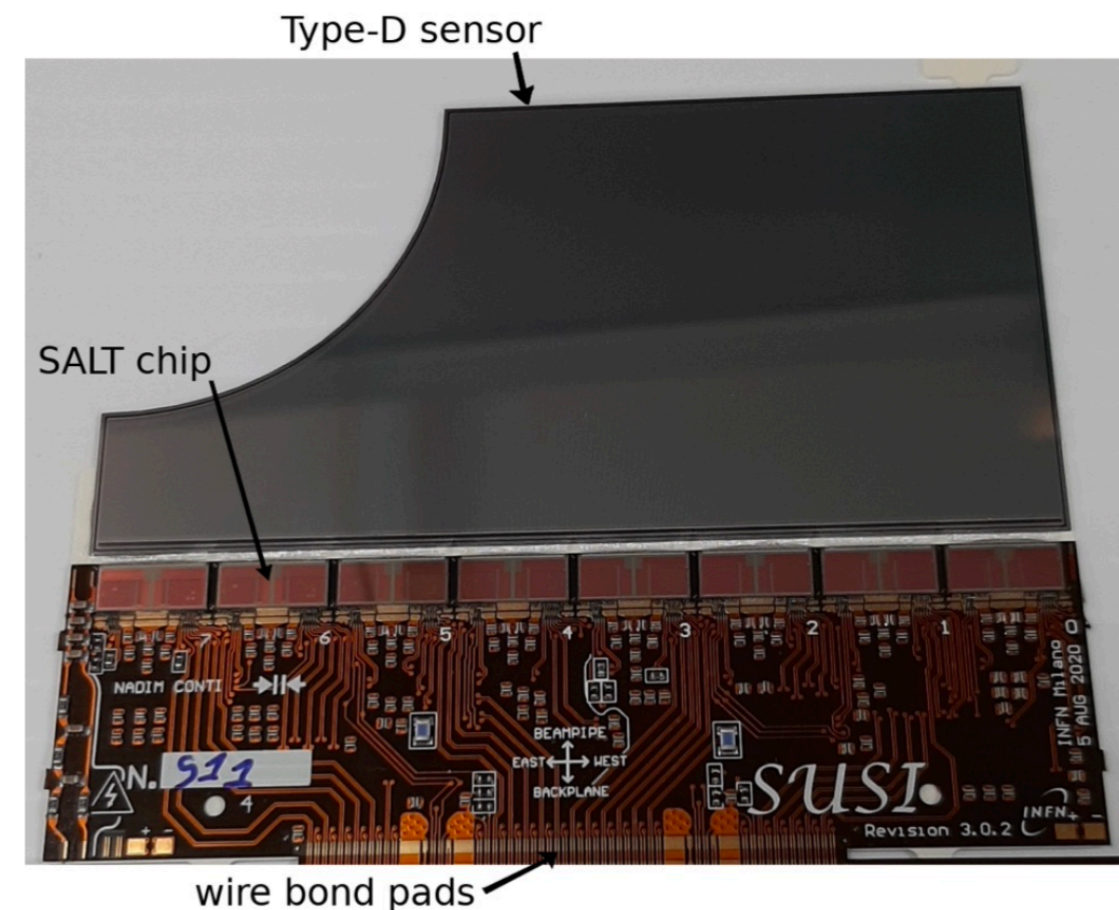
- ▶ Need to determine the sensor operation temperature. E.g. to avoid thermal run-away, the VELO silicon sensors are operated at  $T \lesssim -20 \text{ }^\circ\text{C}$  (400 Mrad), while the UT silicon sensors at  $T \lesssim -5 \text{ }^\circ\text{C}$  (40 Mrad)
- ▶ Simplify the cooling system. No evaporative  $\text{CO}_2$  microchannel cooling. A water-based (+glycol) solution has been proposed by N. Turini. It can reach negative temperatures
- ▶ Alternative solution proposed by Sune without water inside the RP



# Tracker detectors

- ▶ For the tracker detectors after the magnet, 2 possible solutions are proposed: 1) sensors in RPs, 2) sensors in air using a “Hamburg” beam pipe (see Elisabetta’s slides)
- ▶ Silicon pixel and strip detectors could be considered for the tracker stations with larger area and lower rates (20 MHz/cm<sup>2</sup>)

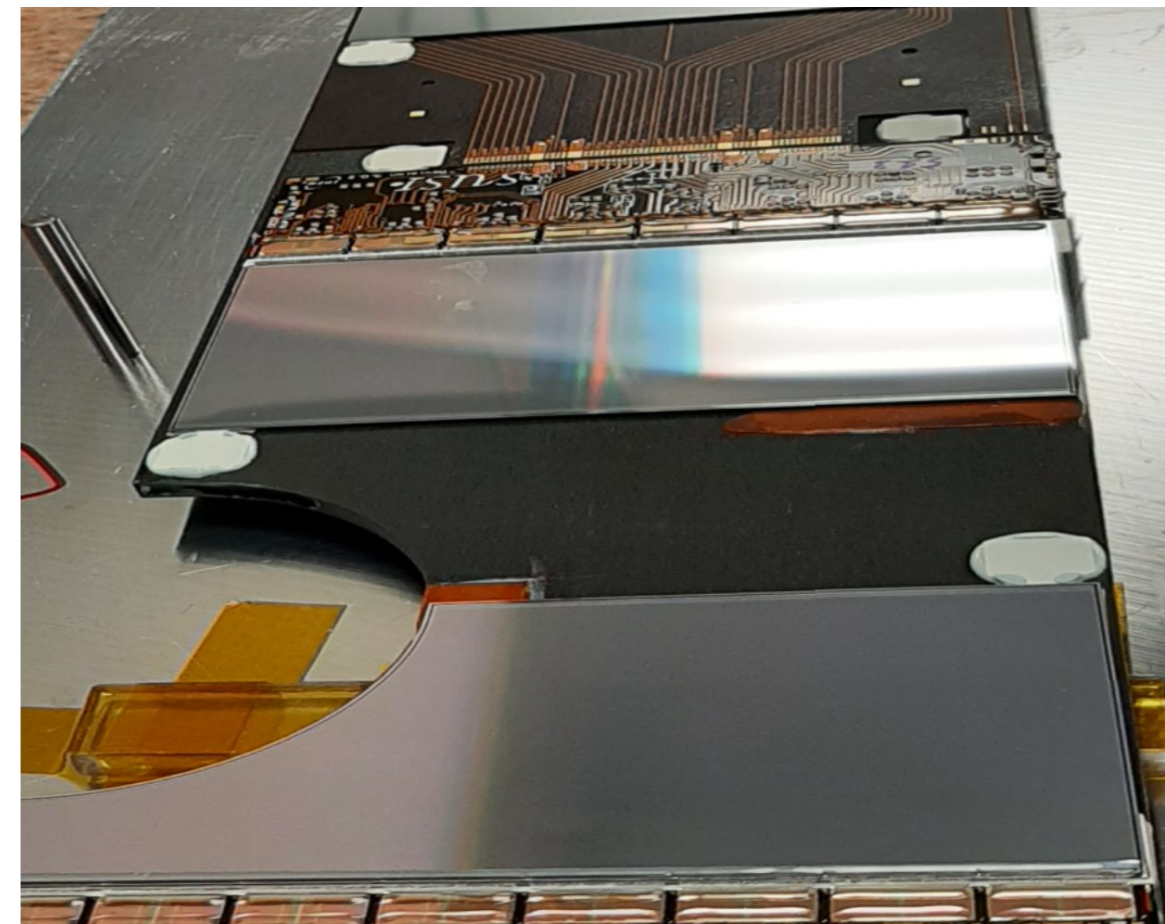
Strip sensor parameter	Rating
silicon type	p-type
thickness	250 μm
active area	51.45x97.35 mm <sup>2</sup>
strip pitch	93.5 μm
strips	1024
full depletion V	200-300 V



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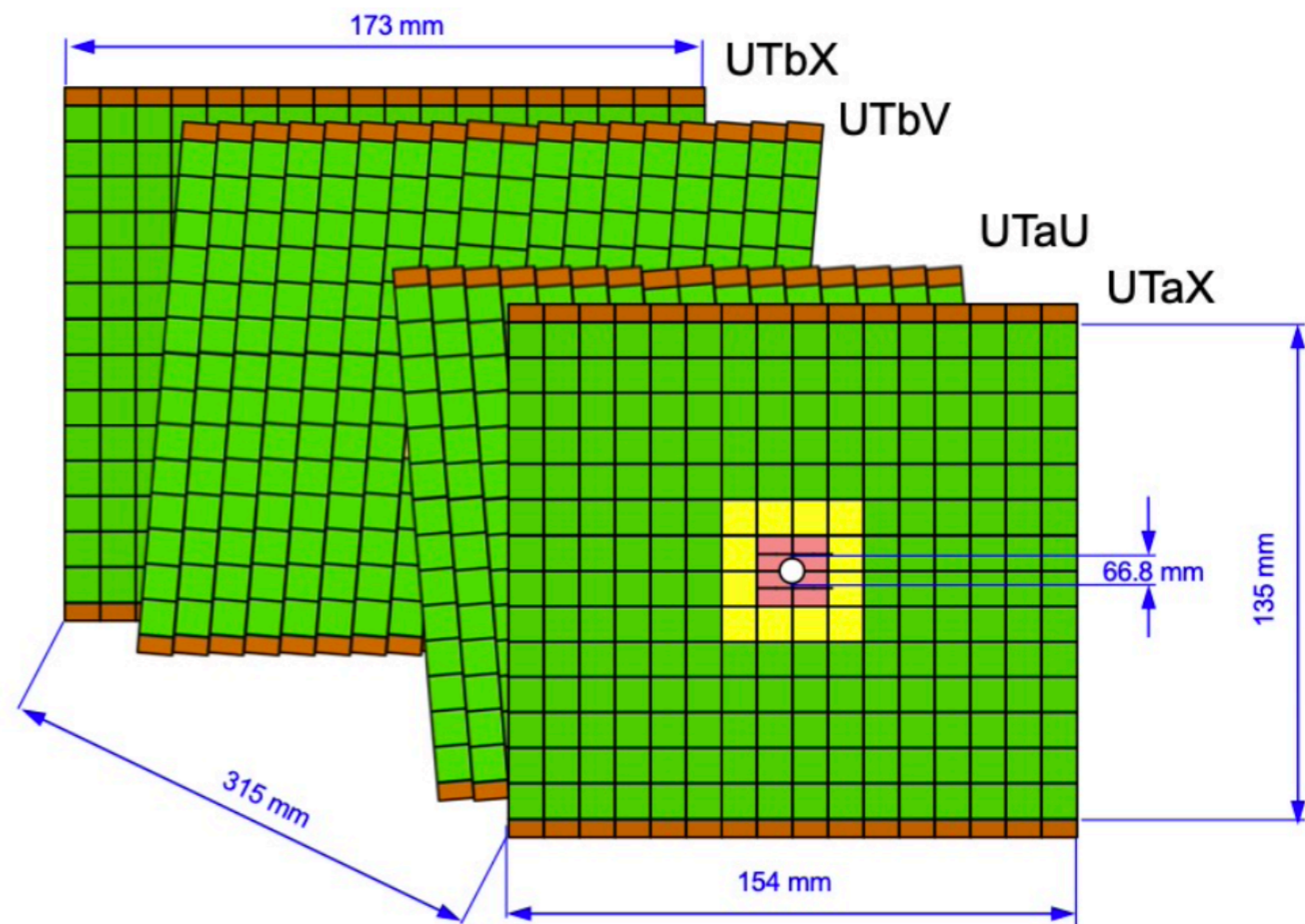
Courtesy of P. Gandini

# SALT chip specifications

Variable	Specification
Technology	TSMC CMOS 130 nm
Channels per ASIC	128
Input / Output pitch	80 $\mu\text{m}$ / 140 $\mu\text{m}$
Total power dissipation	< 768 mW
Radiation hardness	0.3 MGy
Sensor input capacitance	1.6–12 pF
Noise	$\sim 1000 e^- @ 10 \text{ pF} + 50 e^- / \text{pF}$
Maximum cross-talk	Less than 5% between channels
Signal polarity	Both electron and hole collection
Dynamic range	Input charge up to $\sim 30\,000 e^-$
Linearity	Within 5% over dynamic range
Pulse shape and tail	$T_{peak} \sim 25 \text{ ns}$ , amplitude after $2 \times T_{peak} < 5\%$ of peak
Gain uniformity	Uniformity across channels within $\sim 5\%$
ADC bits	6 bits (5 bits for each polarity)
ADC sampling rate	40 MHz
DSP functions	Pedestal and MCM subtraction, zero suppression
Output formats	Non-zero suppressed, zero suppressed
Calibration modes	Analogue test pulses, digital data loading
Output serialiser	Three to five serial e-links, at 320 Mbit/s
Slow controls interface	I2C
Fast digital signals interface	Differential, SLVS

# Strip sensor configuration

- ▶ For momentum measurement it is relevant the measurement of the position in the bending plane
- ▶ LHCb UT silicon strip layers are organised in X-U-V-X configuration. U-V with  $+5^\circ$  and  $-5^\circ$  stereo angle
- ▶ Very good resolution in  $x$ ,  $\sigma_x \approx 25 \mu\text{m}$ , and appreciable in  $y$ :  
 $\sigma_y \approx \sigma_x / \sin \alpha = 290 \mu\text{m}$



# Pixel vs Strip sensors

	Pixel	Strip
Cost per unit area	higher (x 50)	lower
Granularity	55x55 $\mu\text{m}^2$	51.45 cm x 93.5 $\mu\text{m}$
Material budget per layer	1% $x/X_0$	1% $x/X_0$
Radiation hardness (ASIC)	400 Mrad	30 Mrad
Position measurement	2D	1D
Hit resolution	15 $\mu\text{m}$	25 $\mu\text{m}$
Patter recognition	Excellent	Very good

# Summary

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- ▶ A pixel vertex detector based on silicon pixel sensors has been discussed
  - VELO sensors housed inside Roman Pots represent a suitable solution
- ▶ The detectors for the spectrometer have been also discussed
  - Detectors could be positioned outside the beam pipe
  - VELO sensors represent a suitable solution also in this case. Silicon strip detectors can also be used to reduce costs and enlarge the active area